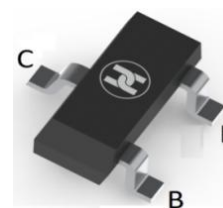


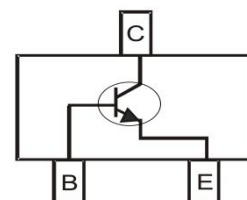
BIPOLEAR TRANSISTOR (NPN)

FEATURES

- Complementary to BCW70
- Low Voltage
- Low Current
- Low Noise
- Surface Mount device



SOT-23



MECHANICAL DATA

- Case: SOT-23
- Case Material: Molded Plastic. UL flammability
- Classification Rating: 94V-0
- Weight: 0.008 grams (approximate)

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

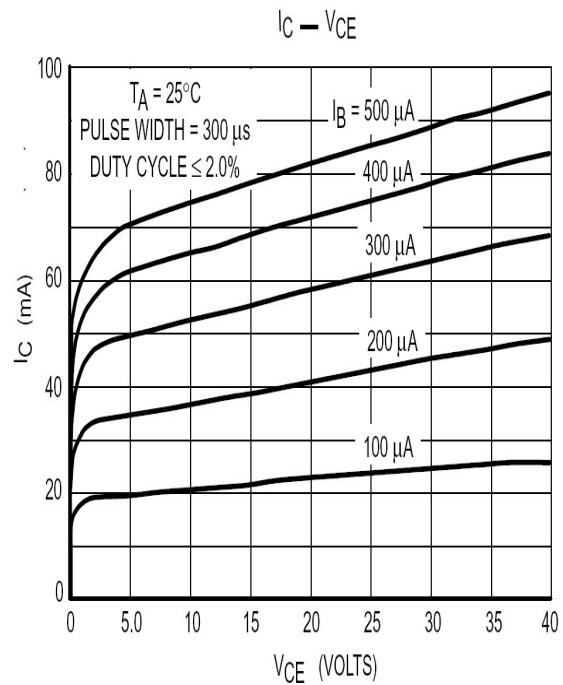
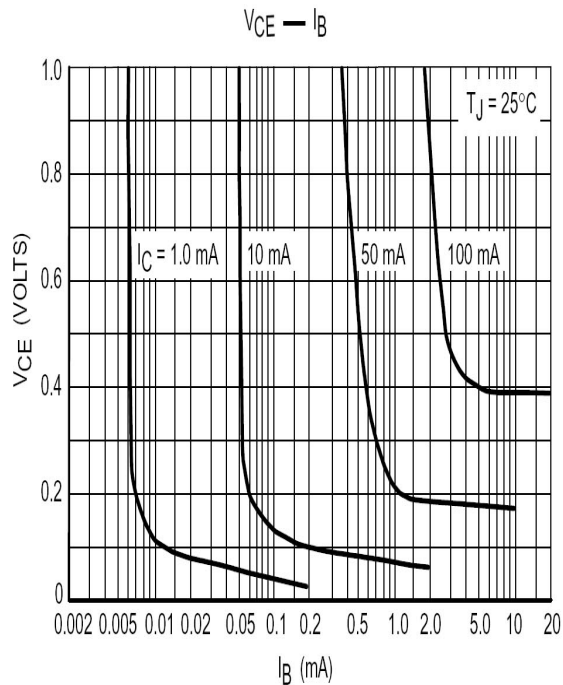
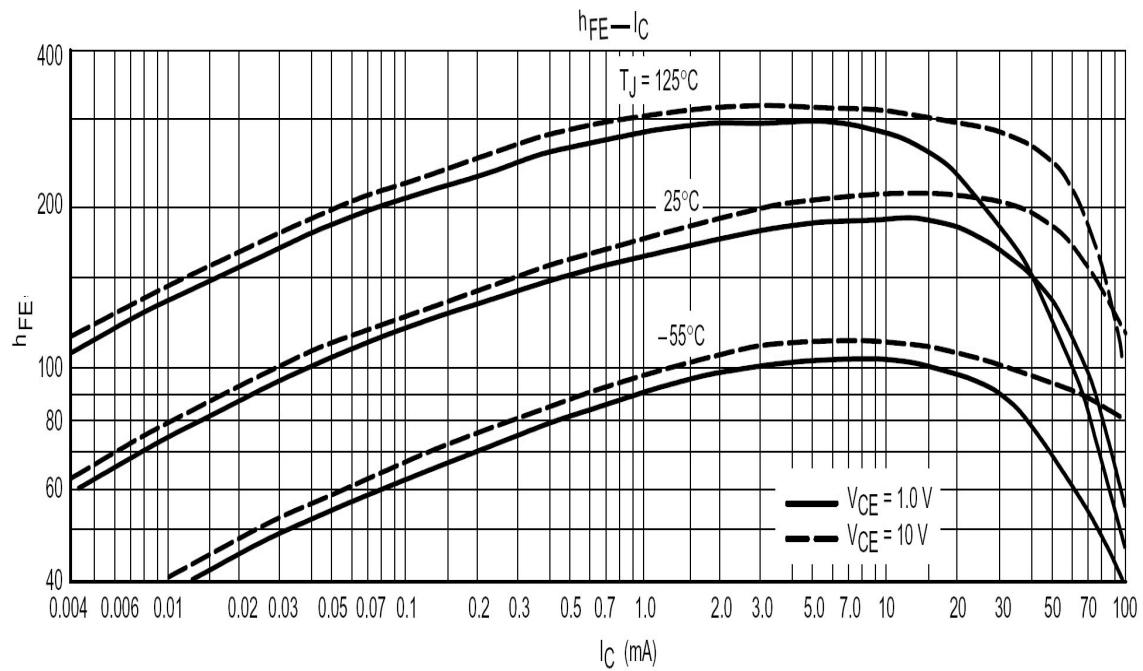
Parameter	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	V_{CEO}	45	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	100	mA
Peak Collector Current	I_{CM}	200	mA
Peak Base Current	I_{BM}	200	mA
Collector Power Dissipation	P_C	250	mW
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55 ~ +150	$^\circ\text{C}$

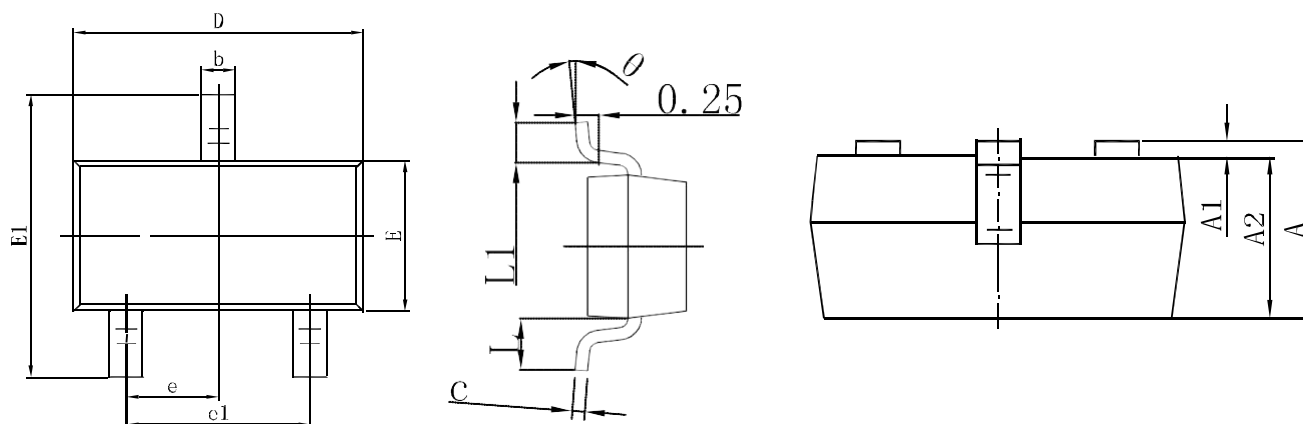
ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Collector-base breakdown voltage	$V_{(BR)CBO}$	50			V	$I_C=100\mu\text{A}$, $I_E=0$
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	45			V	$I_C=0.5\text{mA}$, $I_B=0$
Emitter-base breakdown voltage	$V_{(BR)EBO}$	5			V	$I_E=100\mu\text{A}$, $I_C=0$
Collector cut-off current	I_{CBO}			0.1	μA	$V_{CB}=20\text{V}$, $I_E=0$
Emitter cut-off current	I_{EBO}			0.1	μA	$V_{EB}=5\text{V}$, $I_C=0$
DC current gain	h_{FE1}	200		450		$V_{CE}=5\text{V}$, $I_C=2\text{mA}$
	h_{FE2}		150			$V_{CE}=5\text{V}$, $I_C=0.01\text{mA}$
Collector-emitter saturation voltage	$V_{CE(sat)1}$		0.12	0.25	V	$I_C=10\text{mA}$, $I_B=0.5\text{mA}$
	$V_{CE(sat)2}$		0.21			$I_C=50\text{mA}$, $I_B=2.5\text{mA}$
Base-emitter saturation voltage	$V_{BE(sat)1}$		0.75		V	$I_C=10\text{mA}$, $I_B=0.5\text{mA}$
	$V_{BE(sat)2}$		0.85		V	$I_C=50\text{mA}$, $I_B=2.5\text{mA}$
Base-emitter on voltage	V_{BE}	0.55		0.70	V	$V_{CE}=5\text{V}$, $I_C=2\text{mA}$
Transition frequency	f_T	100			MHz	$V_{CE}=5\text{V}$, $I_C=10\text{mA}$, $f=100\text{MHz}$
Collector output capacitance	C_{ob}		2.5		pF	$V_{CB}=10\text{V}$, $I_E=0$, $f=1\text{MHz}$
Noise figure	NF			10	dB	$V_{CE}=5\text{V}$, $I_C=0.2\text{mA}$, $R_g=2\text{k}\Omega$, $f=1\text{MHz}$

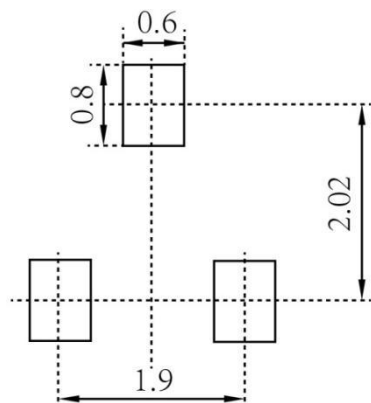
BIPOLAR TRANSISTOR (NPN)

Typical Characteristics



BIPOLAR TRANSISTOR (NPN)
SOT-23 Package Outline Dimensions


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

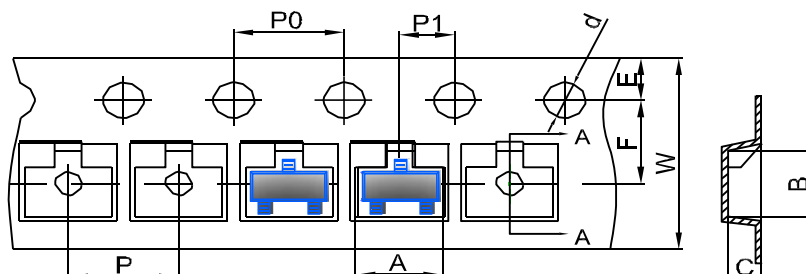
SOT-23 Suggested Pad Layout

Note:

1. Controlling dimension: in millimeters
2. General tolerance: $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only

BIPOLAR TRANSISTOR (NPN)

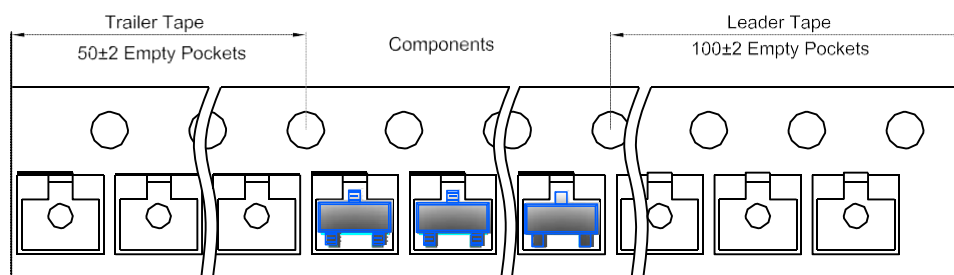
SOT-23 Tape and Reel

SOT-23 Embossed Carrier Tape

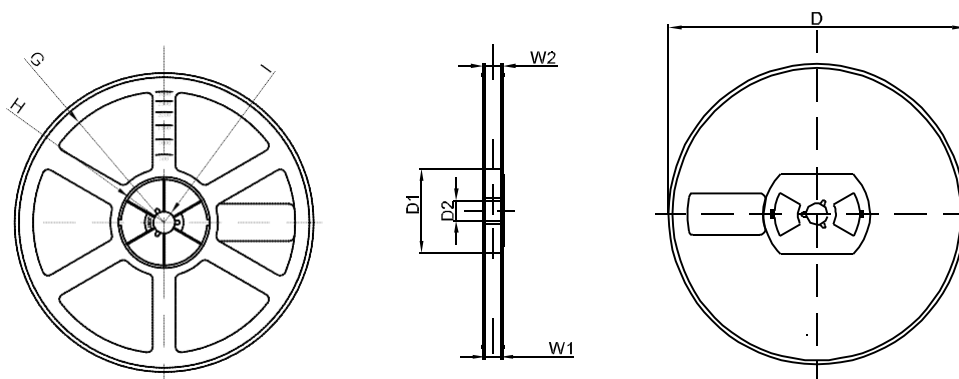


DIMENSIONS ARE IN MILLIMETER										
TYPE	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

SOT-23 Tape Leader and Trailer



SOT-23 Reel



DIMENSIONS ARE IN MILLIMETER								
REEL OPTION	D	D1	D2	G	H	I	W1	W2
7" DIA	Ø178	54.40	13.00	R78	R25.60	R6.50	9.50	12.30
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1